NSN 5961-01-069-8599

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-069-8599 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 15.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 30.00 milliamperes forward current, average absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: